

FGPF4633 330 V PDP Trench IGBT

Features

- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.55 V @ I_C = 70 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

Applications

• PDP TV, Consumer appliances, Lighting

General Description

Using novel trench IGBT technology, Fairchild[®]s new series of trench IGBTs offer the optimum performance for consumer appliances, PDP TV and lighting applications where low conduction and switching losses are essential.



Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		330	V
V _{GES}	Gate to Emitter Voltage		± 30	V
I _{C pulse(1)*}	Collector Current	@ T _C = 25 ^o C	300	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	30.5	W
	Maximum Power Dissipation	@ T _C = 100 ^o C	12.2	W
Tj	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

Symbol	Symbol Parameter		Max.	Units
$R_{\theta JC}$ (IGBT)	(IGBT) Thermal Resistance, Junction to Case		4.1	°C/W
R _{0JA} Thermal Resistance, Junction to Ambient		-	62.5	°C/W

Notes:

(1) Half Sine Wave, D < 0.01, pluse width < 5 μsec * lc_pluse limited by max Tj

April 2013

Device Marking FGPF4633		Device F	Package	ackage Packaging Type	Qty pe	Qty per Tube		Max Qty per Box	
		FGPF4633TU T	TO-220F Tube	50	ea		-		
Electric		actoriation of the	ODT		I		I		
Symbol		acteristics of the Parameter	-	5°C unless otherwise noted	Min.	Тур.	Max.	Unit	
Off Charac				050 4	000				
BV _{CES}		o Emitter Breakdown Voltage		_C = 250 μA	330	-	-	V	
ΔΒV _{CES} ΔΤ _J	Temperati Voltage	are Coefficient of Breakdowr	V _{GE} = 0 V, I	_C = 250 μA	-	0.3	-	V/ºC	
I _{CES}	Collector 0	Cut-Off Current	$V_{CE} = V_{CES}$	V _{GE} = 0 V	-	-	100	μA	
I _{GES}	G-E Leaka	age Current	V _{GE} = V _{GES}	, V _{CE} = 0 V	-	-	±400	nA	
On Charact	teristics								
V _{GE(th)}	G-E Thres	hold Voltage	d Voltage $I_{C} = 250 \ \mu A, \ V_{CE} = V_{GE}$		2.4	3.3	4.0	V	
V _{CE(sat)} Co				I _C = 20 A, V _{GE} = 15 V		1.1	-	V	
			I _C = 40 A, V _C	_{GE} = 15 V	-	1.35	-		
		Collector to Emitter Saturation Voltage		_{GE} = 15 V,	-	1.55	1.8	V	
				_{GE} = 15 V,	-	1.61	-	v	
Dynamic C	haracterist	ics			•				
C _{ies}	Input Capa				-	1715	-	pF	
C _{oes}	Output Ca	pacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz		_	75	-	pF	
C _{res}	Reverse T	ransfer Capacitance			-	55	-	pF	
Switching	Characteris	stics							
t _{d(on)}	Turn-On D	elay Time			-	8	-	ns	
t _r	Rise Time	-	V _{CC} = 200 V		-	30	-	ns	
t _{d(off)}	Turn-Off D	elay Time	R _G = 5 Ω, V Resistive Lo	_{GE} = 15 V ad, T _C = 25ºC	-	52	-	ns	
t _f	Fall Time				-	260	-	ns	
t _{d(on)}	Turn-On D	elay Time			-	8	-	ns	
t _r	Rise Time		$V_{\rm CC} = 200 V$		-	32	-	ns	
t _{d(off)}	Turn-Off D	elay Time		$R_G = 5 \Omega$, $V_{GE} = 15 V$, Resistive Load, $T_C = 125^{\circ}C$		53	-	ns	
t _f	Fall Time				-	341	-	ns	
Q _g	Total Gate	Charge			-	60	-	nC	
Q _{ge}		nitter Charge	─ V _{CE} = 200 V V _{GE} = 15 V	, I _C = 20 A	-	8	-	nC	
Q _{gc}		ollector Charge			_	20	-	nC	

15V

12V

10V

V_{GE} = 8V

6

12

16

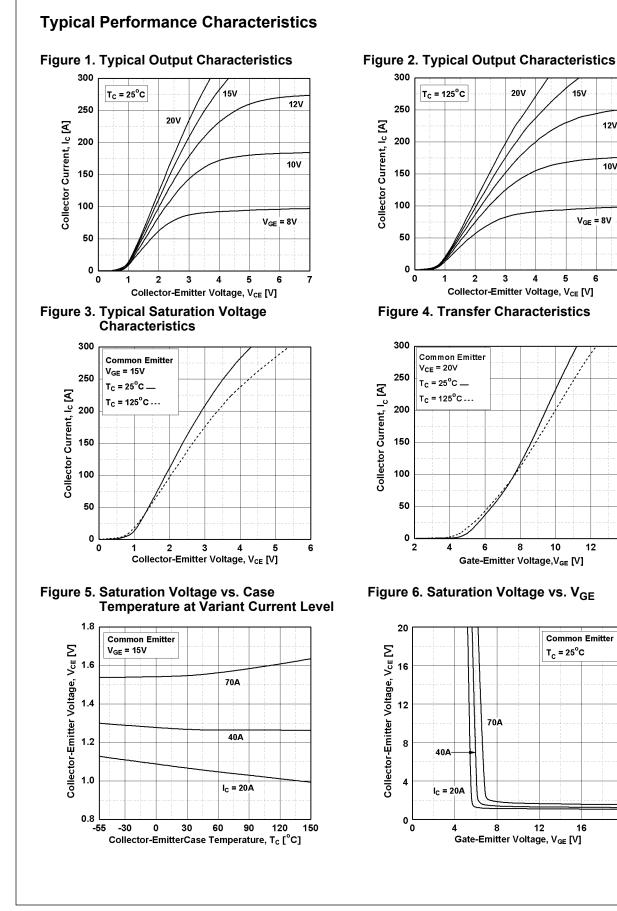
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Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

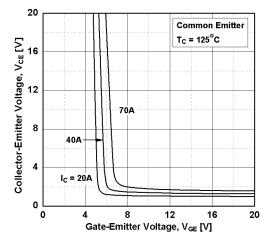
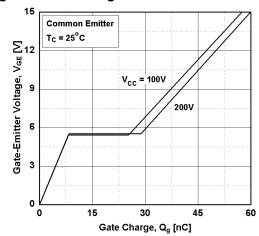


Figure 9. Gate charge Characteristics





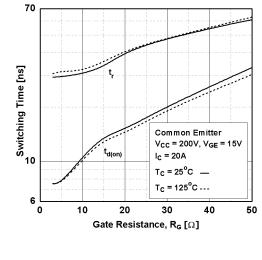


Figure 8. Capacitance Characteristics

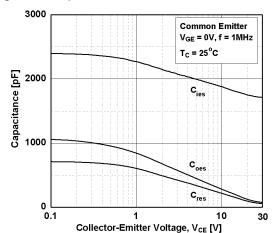


Figure 10. SOA Characteristics

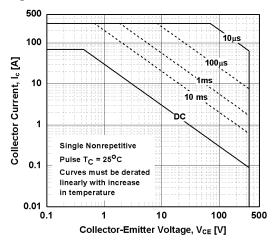
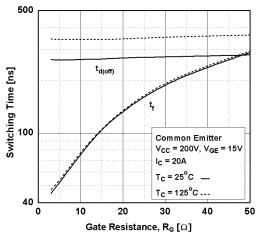
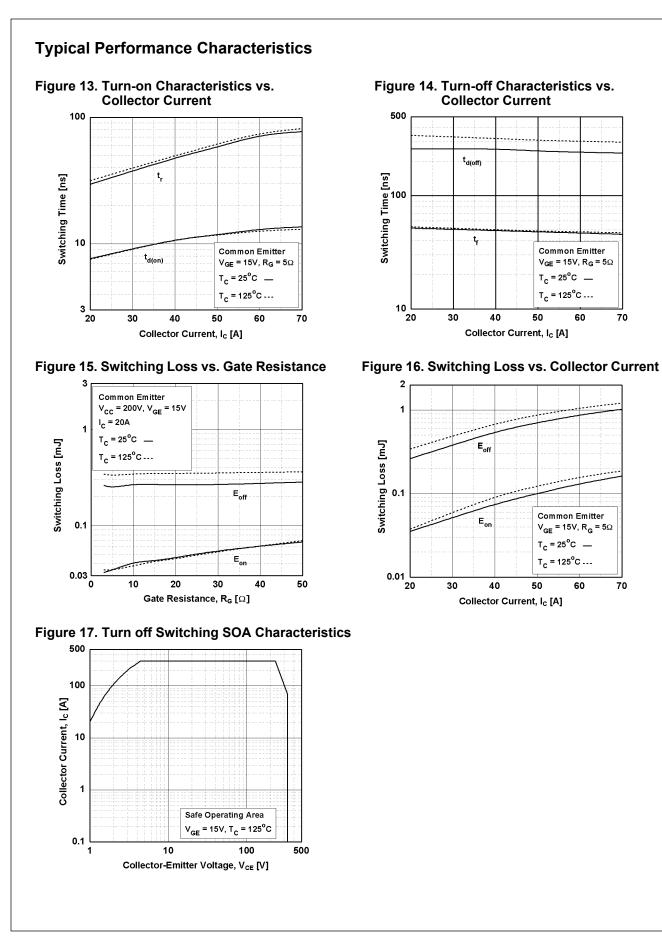
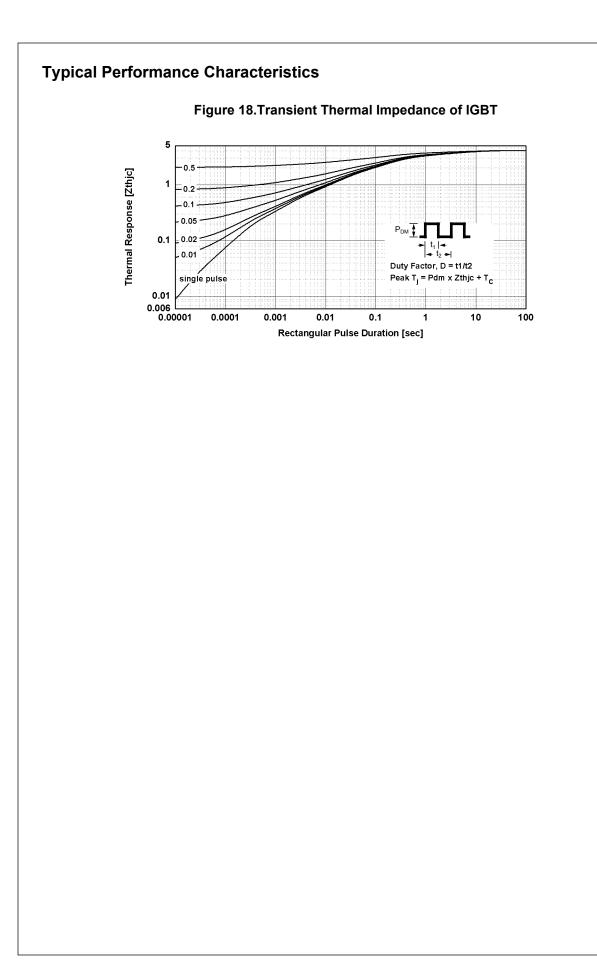
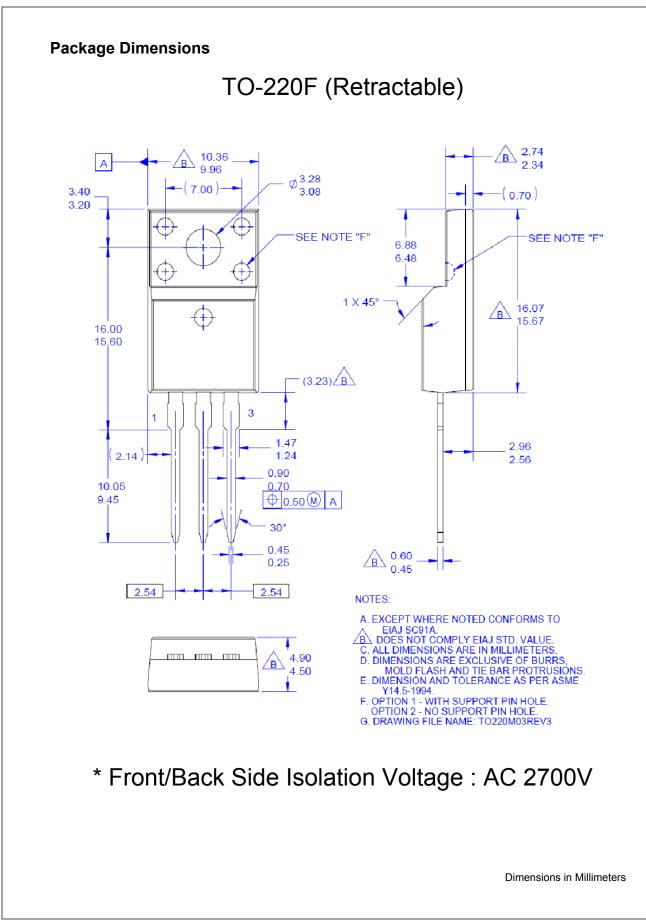


Figure 12. Turn-off Characteristics vs. Gate Resistance











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